

TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

# 2SK246

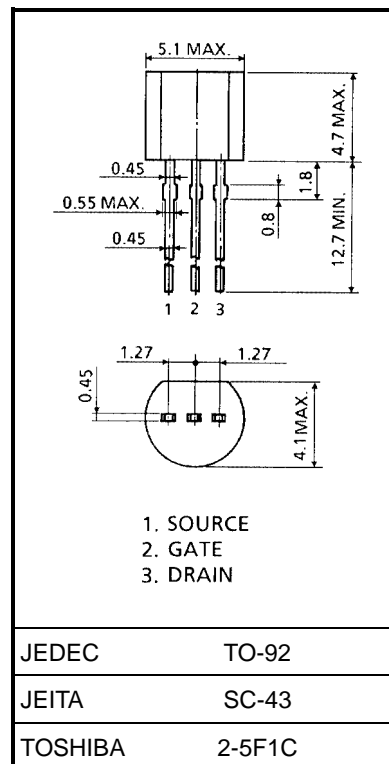
For Constant Current, Impedance  
Converter and DC-AC High Input  
Impedance Amplifier Circuit Applications

Unit: mm

- High breakdown voltage:  $V_{GDS} = -50$  V
- High input impedance:  $I_{GSS} = -1$  nA (max) ( $V_{GS} = -30$  V)

## Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	$V_{GDS}$	-50	V
Gate current	$I_G$	10	mA
Drain power dissipation	$P_D$	300	mW
Junction temperature	$T_j$	125	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55~125	$^\circ\text{C}$



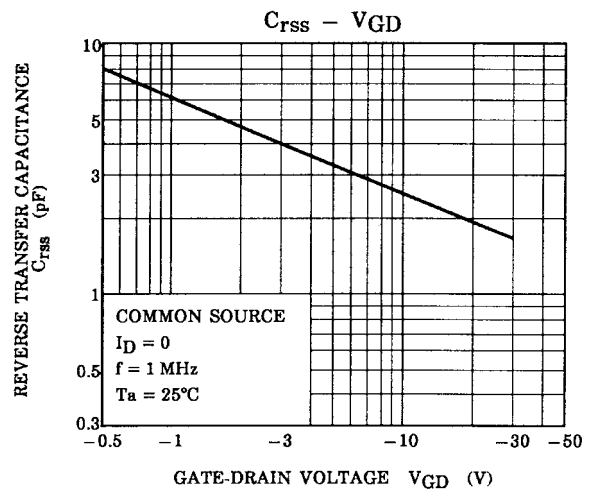
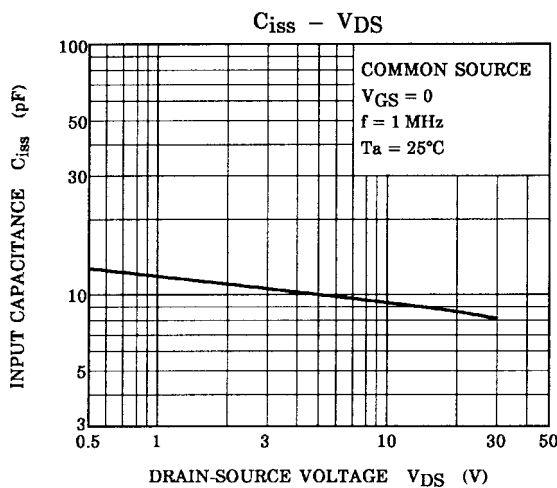
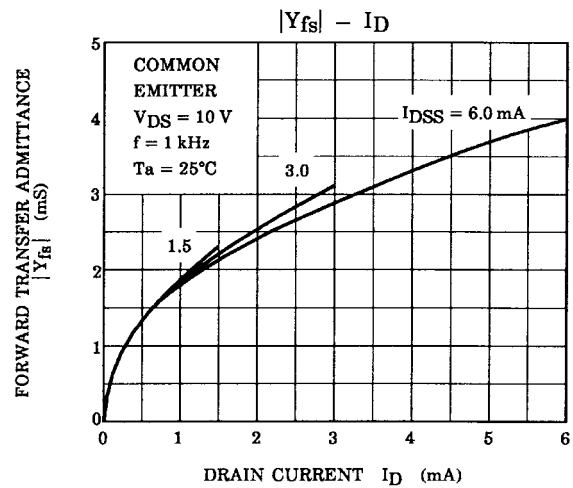
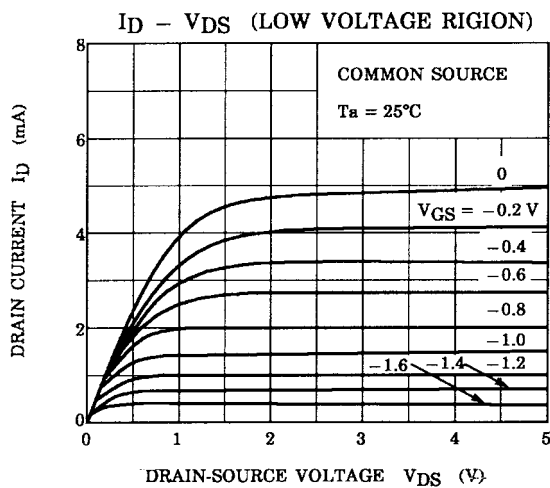
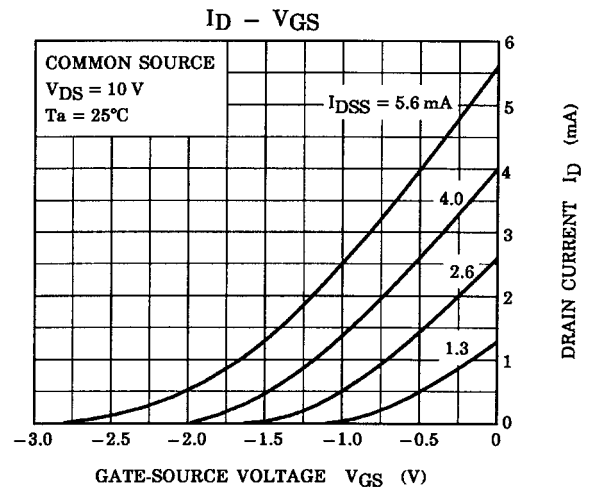
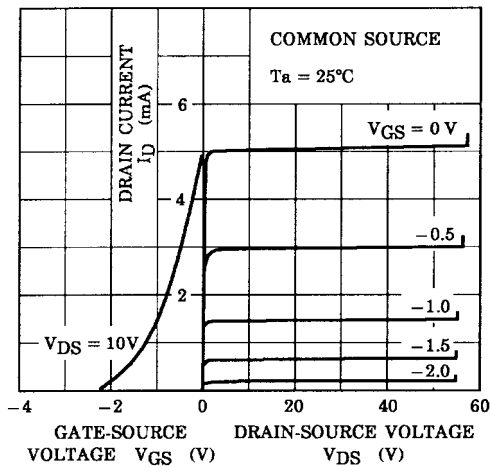
Weight: 0.21 g (typ.)

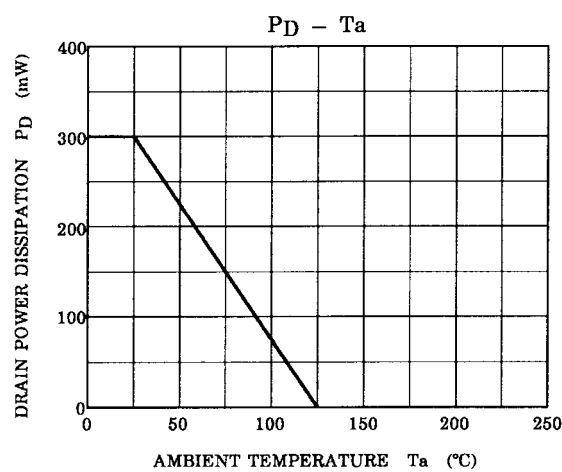
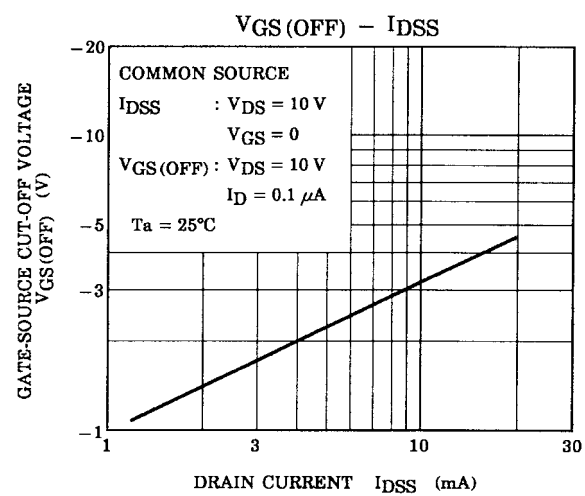
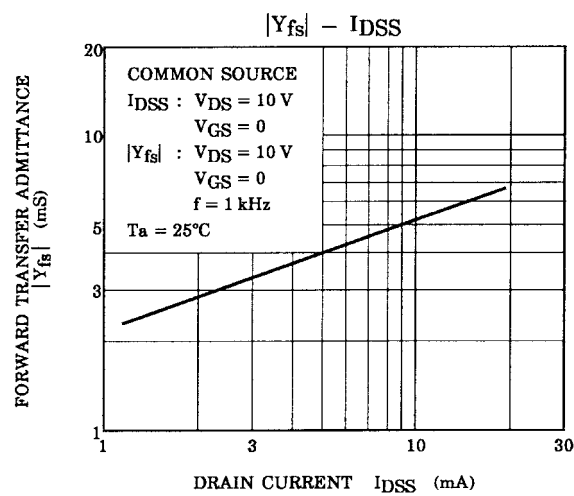
## Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate cut-off current	$I_{GSS}$	$V_{GS} = -30$ V, $V_{DS} = 0$	—	—	-1.0	nA
Gate-drain breakdown voltage	$V_{(BR) GDS}$	$V_{DS} = 0$ , $I_G = -100$ $\mu\text{A}$	-50	—	—	V
Drain current	$I_{DSS}$ (Note)	$V_{DS} = 10$ V, $V_{GS} = 0$	1.2	—	14	mA
Gate-source cut-off voltage	$V_{GS (OFF)}$	$V_{DS} = 10$ V, $I_D = 0.1$ $\mu\text{A}$	-0.7	—	-6.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10$ V, $V_{GS} = 0$ , $f = 1$ kHz	1.5	—	—	mS
Input capacitance	$C_{iss}$	$V_{DS} = 10$ V, $V_{GS} = 0$ , $f = 1$ MHz	—	9.0	—	pF
Reverse transfer capacitance	$C_{rss}$	$V_{DG} = 10$ V, $I_D = 0$ , $f = 1$ MHz	—	2.5	—	pF

Note:  $I_{DSS}$  classification Y: 1.2~3.0 mA, GR: 2.6~6.5 mA, BL: 6~14 mA

STATIC CHARACTERISTICS





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